

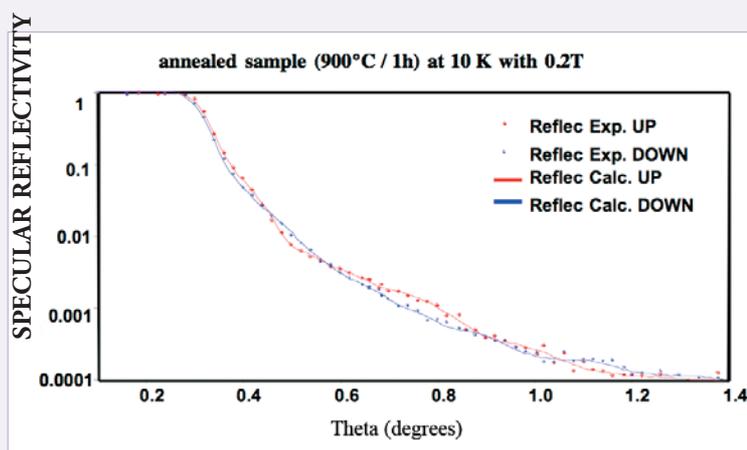
MD shows that while  $\text{Na}^+$  ions have no specific adsorption sites on the clay surface,  $\text{Cs}^+$  ions exhibit a jump diffusion between sites allowing coordination to six oxygen atoms of the adjacent clay layers. In the bulk, on the picosecond-nanosecond timescale, water molecules diffuse by a combination of translational and rotational motion. In the case of clays, this behaviour is necessarily modified by the narrow confinement between two parallel clay layers. Never-the-less, while the water diffusion coefficient in case of a single confined water layer is an order of magnitude lower than in bulk water ( $1-2 \times 10^{-10} \text{ m}^2/\text{s}$ ), in the two-layer clay hydrate the diffusion coefficient is already almost half of the bulk value ( $1 \times 10^{-9} \text{ m}^2/\text{s}$ ,  $D_{\text{bulk}}=2.3 \times 10^{-9} \text{ m}^2/\text{s}$ ). This is seen both in experiment and simulation.

*PhD thesis of N. Malikova (LI2C/ANDRA), [Collaboration LI2C (Université P&M Curie, Paris VI, CNRS) and LLB ] Malikova, Cadène, Marry, Dubois & Turq, J. Phys. Chem. B 110, pp.3206-3214, 2006.*

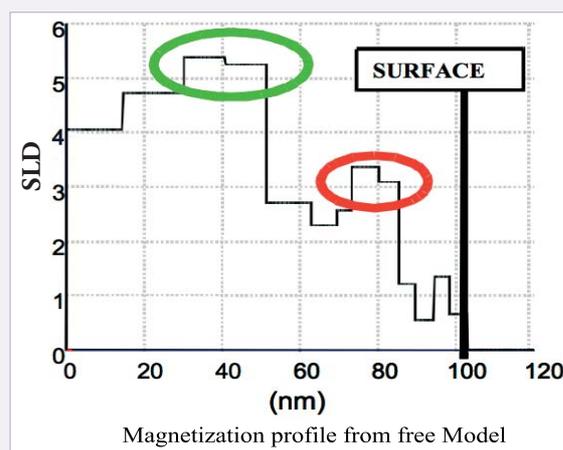
#### [C4. A. Declémy] Ferromagnetic Fe-implanted SiC: New results towards a Diluted Magnetic Semiconductor

SiC is a good candidate for diluted magnetic semiconductors which could be used in spin-electronic devices. It has a wide band-gap (3.1 eV), low spin-orbit coupling, excellent transport properties and has reached a mature state of industrial development. In order to create magnetic SiC, substrates have been implanted with Fe ions at the LMP Univ. Poitiers (at doses of the order of  $5 \cdot 10^{16}/\text{cm}^3$ ). After annealing (700-900°C), a ferromagnetic behavior has been observed with a high Curie temperature (up to 700°C). Polarized neutron reflectivity has allowed to probe the magnetization of the SiC:Fe films as a function of the depth. From the PNR reflectivity (Fig. 1), it is possible to reconstruct the magnetization profile (Fig. 2). The complicated shape of the fitted magnetization profile through the depth of the sample is connected to the multi-implantation process. The measured profile corresponds quite well with the implantation profile which can be simulated with SRIM. The fact that we are dealing with a magnetic semi-conductor needs to be confirmed. Until now, EXAFS shows that there are no Fe atoms in the very near Fe environment which excludes the presence of Fe clusters. The possibility of secondary phases such as  $\text{Fe}_3\text{Si}$  needs to be checked.

*[Collaboration: A. Declémy, M. Drouet, C. Dupeyrat, D. Babonneau, J. Mimault, T. Girardeau, D. Eyidi, M.F. Beaufort, J.P. Eymery, Université de Poitiers, F. Ott, M. Viret, LLB/SPEC Saclay.]*



**Figure 1:** polarized neutron reflectivity of an SiC:Fe sample measured at 10K (fits in solid lines)



**Figure 2:** Reconstruction of the Fe implantation profile from the PNR. The fit is very close to the calculated implantation profile

#### [C5. V. Klošek] A compact tensile machine for in situ neutron diffraction study of materials under external loading

In order to characterize the behaviour of materials under mechanical loading, a very compact tensile machine was recently developed at LPM TM. This machine is designed to be mounted on the Eulerian cradles of G5.2 and 6T1 diffractometers: to allow a huge variety of sample orientations, its frame consists in two side columns on which are fixed the plates supporting the tensile heads (Fig. 1). It thus now becomes possible to analyse elastic and plastic behaviours of materials during a tensile test by in situ neutron diffraction. This machine is an incomparable tool to study deformation mechanisms under external loading of materials: macro- and micro-strains, texture or stored energy can now be measured as a function of applied load (up to 30 kN). First tests were performed on a brass (Cu-Zn) alloy sample. Figure 2 shows the (111) diffracted peaks recorded on G5.2 at three different loadings, with their corresponding FWHM ( $\lambda = 3.03 \text{ \AA}$ ). At low strain, the peak is essentially shifted toward lower angles (elastic deformation mainly). At higher strain, the peak broadens, traducing the plastic deformation of the material.

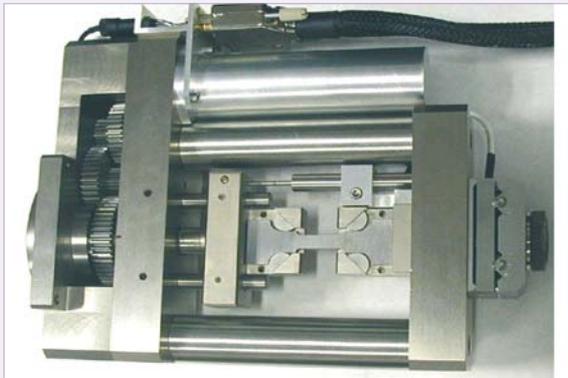


Figure 1: the tensile machine, equipped with a sample

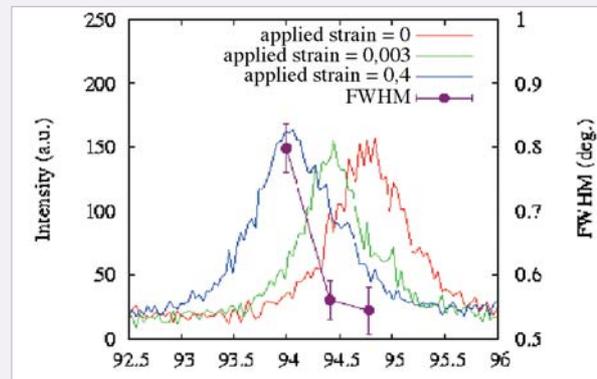


Figure 2: (111) peaks and FWHM recorded on G5.2 for several loadings

[Collaboration: V. Klosek, M.H. Mathon, LLB; V. Ji, LIM-ENSAM, Paris; R. Chiron, LPMTM, Villetaneuse]

#### [C6. S. Jakani] Deformation and recrystallization mechanisms of CuSn alloys (bronze)

The optimization of the macroscopic properties requires the comprehension of the deformation and recrystallization mechanisms. In the case of the copper and of its alloys, the deformation step conditions mainly the mechanisms of recrystallization. Neutron diffraction, performed on 6T1, was used to characterize the deformation texture, stored energy after various rates of rolling (between 0 and 90% of deformation) and the activation energy of recrystallization with “in situ” measurements. The addition of tin (4 to 9%) in pure copper lowers the stacking fault energy. Thus, it is not astonishing to observe a texture of deformation primarily consisted of the a fibre (with the Brass and Goss components). During cold rolling, stored energy increases with the deformation rate but contrary to the case of pure copper and brasses, its distribution is homogeneous between the various crystallographic orientations. A light increase of energy is observable with the tin content. Measurements of kinetics of recrystallization reveal that the energy of activation of the recrystallization process decrease with the deformation rate but remains much more important than in pure copper. The recrystallization is accompanied by the development of the orientations C {112} <11-1> and G {110} <001>. These results show that recrystallization is not only interpretable by stored energy but that the kinetic aspect via the grain boundaries mobility is a prevalent factor in the presence of tin. The presence of an element of addition can then reinforce the energy stored by decreasing the mobility of dislocations and thus act on the dynamic phase of restoration. By the same mechanism, the recrystallization is slowed down. The copper alloys thus present distinct behaviours, a priori depend on the nature of the element of addition which acts differently on the mechanisms of deformation and the mobility of dislocations and the grain boundaries.

[Collaboration: S. Jakani, S. Melusson, M.H. Mathon, LLB]

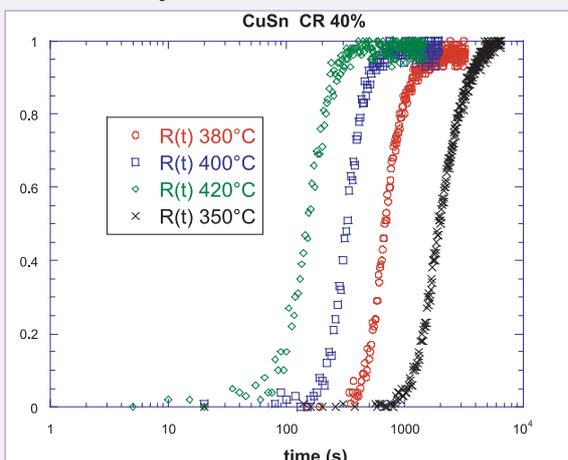


Figure 1: Recrystallization kinetic on the CuSn4% cold rolled up 40%

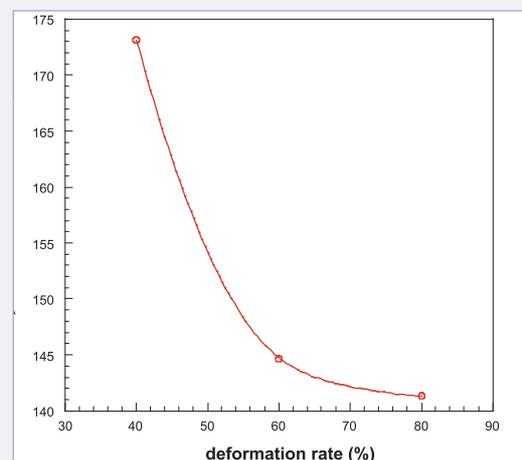


Figure 2: Recrystallization activation energy (kJ/mol) versus the deformation rate.